

# 2.5V SINGLE DATA RATE 1:10 CLOCK BUFFER TERABUFFER™ JR.

IDT5T9070

#### **FFATURFS**:

- · Optimized for 2.5V LVTTL
- Guaranteed Low Skew < 25ps (max)</li>
- Very low duty cycle distortion < 300ps (max)</li>
- High speed propagation delay < 2ns. (max)</li>
- · Up to 200MHz operation
- · Very low CMOS power levels
- · Hot insertable and over-voltage tolerant inputs
- · 1:10 fanout buffer
- 2.5V VDD
- · Available in TSSOP package

## **APPLICATIONS:**

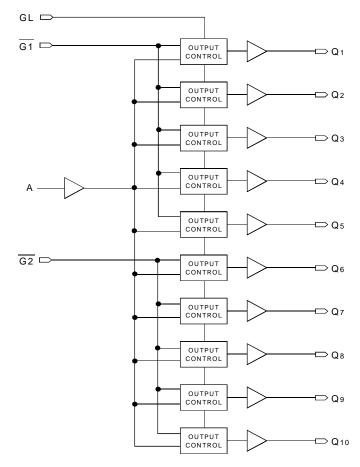
· Clock and signal distribution

## **DESCRIPTION:**

The IDT5T9070 2.5V single data rate (SDR) clock buffer is a single-ended input to ten single-ended outputs buffer built on advanced metal CMOS technology. The SDR clock buffer fanout from a single input to ten single-ended outputs reduces the loading on the preceding driver and provides an efficient clock distribution network.

The IDT5T9070 has two output banks that can be asynchronously enabled/disabled. Multiple power and grounds reduce noise.

## **FUNCTIONAL BLOCK DIAGRAM**

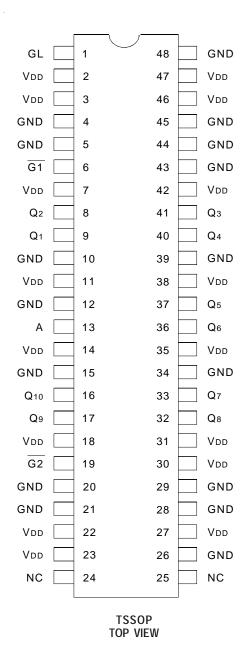


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INDUSTRIAL TEMPERATURE RANGE

OCTOBER 2002

## PIN CONFIGURATION



## ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VDD	VDD Power Supply Voltage		V
Vı	Input Voltage	-0.5 to +3.6	V
Vo	Output Voltage	-0.5 to VDD +0.5	V
Tstg	Storage Temperature	-65 to +165	°C
TJ	Junction Temperature	150	°C

#### NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# CAPACITANCE $^{(1)}$ (TA = +25°C, F = 1.0MHz)

Symbol	Parameter	Min	Тур.	Max.	Unit
CIN	Input Capacitance	1	6	-	pF

#### NOTE:

1. This parameter is measured at characterization but not tested.

## RECOMMENDED OPERATING RANGE

Symbol	Description	Min.	Тур.	Max.	Unit
TA	Ambient Operating Temperature	-40	+25	+85	°C
VDD	Internal Power Supply Voltage	2.3	2.5	2.7	V

## **PIN DESCRIPTION**

Symbol	I/O	Туре	Description
А	I	LVTTL	Clockinput
G1	Ι	LVTTL	Gate for outputs $Q_1$ through $Q_5$ . When $\overline{G1}$ is LOW, these outputs are enabled. When $\overline{G1}$ is HIGH, these outputs are asynchronously disabled to the level designated by $GL^{(1)}$ .
G2	I	LVTTL	Gate for outputs $Q_6$ through $Q_{10}$ . When $\overline{G2}$ is LOW, these outputs are enabled. When $\overline{G2}$ is HIGH, these outputs are asynchronously disabled to the level designated by $GL^{(1)}$ .
GL	I	LVTTL	Specifies output disable level. If HIGH, the outputs disable HIGH. If LOW, the outputs disable LOW.
Qn	0	LVTTL	Clockoutputs
Vdd		PWR	Power supply for the device core, inputs, and outputs
GND		PWR	Power supply return for power

#### NOTE:

# DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE (1)

Symbol	Parameter	Test Conditions	Min.	Typ. <sup>(4)</sup>	Max	Unit
Іін	Input HIGH Current	$V_{DD} = 2.7V$ $V_{I} = V_{DD}/GND$	_	_	±5	μΑ
lıL	Input LOW Current	$V_{DD} = 2.7V$ $V_{I} = GND/V_{DD}$	_	_	±5	
Vik	Clamp Diode Voltage	V <sub>DD</sub> = 2.3V, I <sub>IN</sub> = -18mA	_	- 0.7	- 1.2	V
Vin	DC Input Voltage		- 0.3		+3.6	V
ViH	DC Input HIGH <sup>(2)</sup>		1.7		_	V
VIL	DC Input LOW <sup>(3)</sup>		_		0.7	V
Vон	Output HIGH Voltage	loн = -12mA	VDD - 0.4		_	V
		Іон = -100μΑ	VDD - 0.1		_	V
Vol	Output LOW Voltage	IoL = 12mA	_		0.4	V
		IoL = 100μA	_		0.1	V

#### NOTES:

- 1. See RECOMMENDED OPERATING RANGE table.
- 2. Voltage required to maintain a logic HIGH.
- 3. Voltage required to maintain a logic LOW.
- 4. Typical values are at V<sub>DD</sub> = 2.5V, +25°C ambient.

<sup>1.</sup> Because the gate controls are asynchronous, runt pulses are possible. It is the user's responsibility to either time the gate control signals to minimize the possibility of runt pulses or be able to tolerate them in down stream circuitry.

## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Тур.	Max	Unit
IDDQ	Quiescent Vdd Power Supply Current	VDD = Max., Reference Clock = LOW	1.5	2	mA
		Outputs enabled, All outputs unloaded			
IDDD	Dynamic Vdd Power Supply	VDD = Max., VDD = Max., CL = OpF	150	200	μΑ/MHz
	Current per Output				
Ітот	Total Power Vdd Supply Current	VDD = 2.5V., Freference clock = 100MHz, CL = 15pF	70	90	mA
		VDD = 2.5V., Freference clock = 200MHz, CL = 15pF	100	150	

#### NOTE:

1. The termination resistors are excluded from these measurements.

## INPUT AC TEST CONDITIONS

Symbol	Parameter	Value	Units
VIH	Input HIGH Voltage	Vdd	V
VIL	Input LOW Voltage	0	V
Vтн	VTH Input Timing Measurement Reference Level <sup>(1)</sup>		V
tr, tr	Input Signal Edge Rate <sup>(2)</sup>	2	V/ns

#### NOTES:

- 1. A nominal 1.25V timing measurement reference level is specified to allow constant, repeatable results in an automatic test equipment (ATE) environment.
- $2. \ The input signal edge \ rate \ of \ 2V/ns \ or \ greater \ is \ to \ be \ maintained \ in \ the \ 10\% \ to \ 90\% \ range \ of \ the \ input \ waveform.$

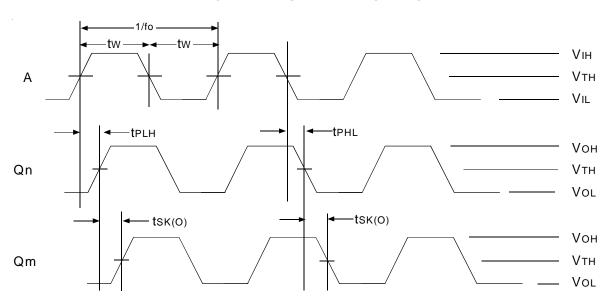
## AC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE<sup>(4)</sup>

Symbol	Parameter	Min.	Тур.	Max	Unit
Skew Parameters	•				
tsk(o)	Same Device Output Pin-to-Pin Skew <sup>(1)</sup>	_	_	25	ps
tsk(p)	Pulse Skew <sup>(2)</sup>	_	_	300	ps
tsk(pp)	Part-to-Part Skew <sup>(3)</sup>	_	_	300	ps
Propagation Delag	у			•	•
<b>t</b> PLH	Propagation Delay A to Qn	_	_	2	ns
<b>t</b> PHL					
tr	Output Rise Time (20% to 80%)	350	_	850	ps
t <sub>F</sub>	Output Fall Time (20% to 80%)	350	_	850	ps
fo	Frequency Range	_	_	200	MHz
Output Gate Enab	le/Disable Delay	-			
tpge	Output Gate Enable to Qn	_	_	3.5	ns
tpgp	Output Gate Enable to Qn Driven to GL Designated Level	_	_	3	ns

#### NOTES:

- 1. Skew measured between all outputs under identical input and output transitions and load conditions on any one device.
- 2. Skew measured is the difference between propagation delay times tehl and tell of any output under identical input and output transitions and load conditions on any one device.
- 3. Skew measured is the magnitude of the difference in propagation times between any outputs of two devices, given identical transitions and load conditions at identical Vpp levels and temperature.
- 4. Guaranteed by design.

## **ACTIMING WAVEFORMS**

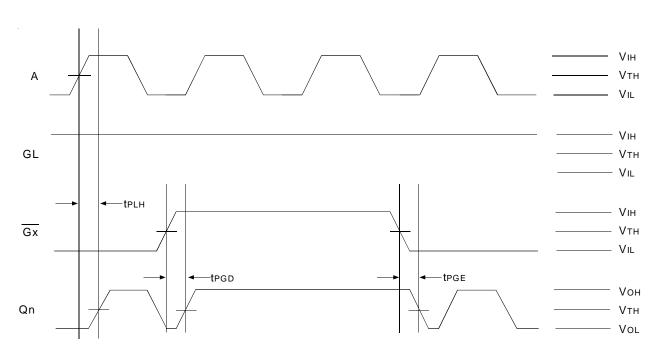


Propagation and Skew Waveforms

NOTE: Pulse Skew is calculated using the following expression:

$$tsk(P) = |tPHL - tPLH|$$

where tphl and tplh are measured on the controlled edges of any one output from rising and falling edges of a single pulse. Please note that the tphl and tplh shown are not valid measurements for this calculation because they are not taken from the same pulse.

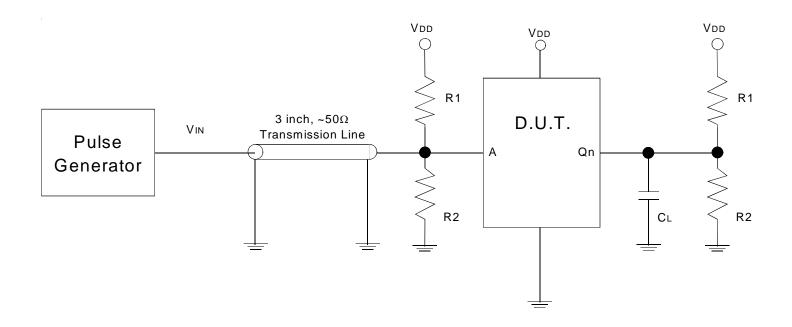


Gate Disable/Enable Runt Pulse Generation

#### NOTE:

As shown, it is possible to generate runt pulses on gate disable and enable of the outputs. It is the user's responsibility to time their  $\overline{Gx}$  signals to avoid this problem.

# **TEST CIRCUIT AND CONDITIONS**

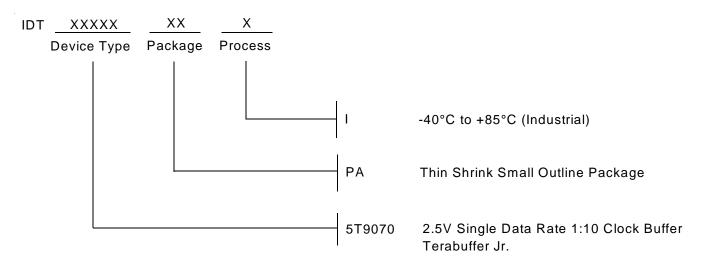


Test Circuit for Input/Output

# INPUT/OUTPUT TEST CONDITIONS

Symbol	$V_{DD} = 2.5V \pm 0.2V$	Unit
VTH	V <sub>DD</sub> / 2	V
R1	100	Ω
R2	100	Ω
CL	15	pF

## ORDERING INFORMATION





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